

## DECLARATION FOR PATENT APPLICATION

As a below named inventor, I declare:  
 that I verily believe myself to be the original, first and sole (if only one  
 individual inventor is listed below) or an original, first and joint inventor  
 (if more than one individual inventor is listed below) of the invention in

SEMICONDUCTOR INTEGRATED CIRCUIT

the specification of which is attached hereto unless the following box is  
 checked.

☒ was filed on March 12, 2004 as United States Application  
 or PCT International Application No. 10/798,402, and  
 was amended on \_\_\_\_\_ (if applicable).

I hereby state that I have reviewed and understand the contents of the above  
 identified specification, including the claims, as amended by any amendment  
 referred to above.

I acknowledge the duty to disclose information of which is material to pat-  
 entability as defined in 37 CFR 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365  
 (b) of any foreign application(s) for patent or inventor's certificate, or  
 35 U.S.C. 365(a) of any PCT International application which designated at  
 least one country other than the United States, listed below and have also  
 identified below any foreign application for patent or inventor's certifi-  
 cate, or PCT International application having a filing date before that of the  
 application on which priority is claimed:

| <u>Country</u> | <u>Category</u> | <u>Application No.</u> | <u>Filing Date</u> | <u>Priority Claim</u> |
|----------------|-----------------|------------------------|--------------------|-----------------------|
| Japan          | Patent          | 2003-379993            | November 10, 2003  | Yes                   |

I hereby appoint the registrants of Oblon, Spivak, McClelland,  
 Maier & Neustadt, P.C., 1940 Duke Street, Alexandria, Virginia 22314,  
 Customer No. 22850, or any one of them. Send correspondence to Oblon,  
 Spivak, McClelland, Maier & Neustadt, P. C., 1940 Duke Street,  
 Alexandria, Virginia 22314, Telephone No. (703) 413-3000.

I declare further that all statements made herein of my own knowledge are  
 true and that all statements made on information and belief are believed to  
 be true; and further that these statements were made with the knowledge that  
 willful false statements and the like so made are punishable by fine or im-  
 prisonment, or both, under Section 1001 of Title 18 of the United States  
 Code and that such willful false statements may jeopardize the validity of  
 the application or any patent issued thereon.



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I declare further that my mailing address is at c/o  
Intellectual Property Division, Toshiba Corporation, 1-1, Shibaura  
1-chome, Minato-ku, Tokyo 105-8001, Japan; and  
that my citizenship and residence are as stated below next to my name:

Inventor: (Signature)DateResidenceDate: **APR. - 8. 2004**

*Nobutaka Kitagawa*  
Nobutaka Kitagawa

Citizen of: JapanMachida-shi, JapanDate:Citizen of: JapanDate:Citizen of: JapanDate:Citizen of: JapanDate:Citizen of: JapanDate:Citizen of: JapanDate:Citizen of: JapanDate:Citizen of: Japan